EAST Search History

EAST Search History (Prior Art)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S494	380	438/519,522.ccls.	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/01/28 15:52
S495	89	amorph$5 and 438/519,522. ccls.	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/01/28 15:54
S496	87	amorph$5 and (heat$3 or thermal or anneal$3) and 438/519,522.ccls.	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/01/28 16:03
S498	6	amorph$5 same (heat$3 or thermal or anneal$3) and pn and 438/519,522.ccls.	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/01/28 16:04
S497	57	amorph$5 same (heat$3 or thermal or anneal$3) and 438/519,522.ccls.	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/01/28 16:04
S499	10	amorph$5 same (heat$3 or thermal or anneal$3) and pn and 438/519-522.ccls.	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/01/28 16:11
S500	540	438/308.ccls.	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/01/28 17:24
S501	814	438/162-163.ccls.	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/01/28 18:05
S503	16	amorphous and first near conductivity depth ((anneal $3 and reanneal$3) or (heat $3 and reheat$3)or (first and second) near (heat$3 or anneal$3 or thermal)) restor $5 and (crystall$7 or recrystall$7)and junction	US-PGPUB; USPAT; USOCR; FPRS	AND	ON	2010/01/28 18:32
S504	15	"6074937"	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/01/28 19:11
S505	2	"08203842"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/28 19:17
S506	22	"5602045"	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/01/28 19:33

S508	3	"04058524"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/28 19:35
S507	1	"04058524"	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/01/28 19:35
S509	3	"06089869"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/28 19:43
S510	3	"05190850"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/28 19:44
S511	3	"04058524"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/28 19:54
S512	2	"2004235280"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/28 19:56
S514	21	"6287925"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/28 19:57
S513	13	"6555439"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/28 19:57
S518	21	("5399506" | "5976956" | "6037640").PN. OR ("6287925").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2010/01/28 21:36
S519	24	"6251757"	US-PGPUB; USPAT; USOCR; FPRS	WITH	ON	2010/01/28 21:42
S520	13	"6680250"	US-PGPUB; USPAT; USOCR; FPRS	WITH	ON	2010/01/28 21:43

S521	4	("5602045" | "6074937").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/28 22:00
S523	23	"5602045"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/28 22:01
S522	16	"6074937"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/28 22:01
S524	4	"557746".ap.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/28 22:05
S525	1143	257/E21.324.ccls.	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/01/29 09:42
S526	1137	257/E21.324.ccls. and @ad<"200400331"	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/01/29 09:49
S527	729	257/E21.324.ccls. and @ad<"20040331"	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/01/29 09:50
S528	667	257/E21.336.ccls. and @ad<"200400331"	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/01/29 10:09
L1	4199	438/301-308.ccls. and @ad<"20040331"	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/01/29 10:55
L2	989	(pre$amorphiz$5 or amorphous or amorphiz$3) and 438/301-308.ccls. and @ad<"20040331"	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/01/29 10:56
L4	2	(pre$amorphiz$5 or amorphous or amorphiz$3) same depth same first near conductivity and (heat$3 or thermal or anneal$3)same (restor$5 or repair$3 or crystall$5 or re$crystall$3) same depth and ion same second near conductivity and (heat$3 or thermal or anneal$3)and (SPE or solid near phase near epitaxy)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/29 11:52

L3	3660	(pre$amorphiz$5 or amorphous or amorphiz$3) same depth same first near conductivity and (heat$3 or thermal or anneal$3)same (restor$5 or repair$3 or crystall$5 or re$crystall$3) same depth and ion same second conductivity and (heat$3 or thermal or anneal $3)and (SPE or solid near phase near epitaxy)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/29 11:52
L5	6	(pre$amorphiz$5 or amorphous or amorphiz$3) same depth same first near conductivity and (heat$3 or thermal or anneal$3)same (restor$5 or repair$3 or crystall$5 or re$crystall$3) same depth and ion same second near conductivity and (heat$3 or thermal or anneal$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/29 12:09
L6	22	("6153455" | "6238960" | "6251761" | "6287924" | "6361874" | "6365476" | "6368947" | "6380044" | "6420264" | "6472277" | "6551888" | "6555439" | "6559015").PN. OR ("6642122").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2010/01/29 12:31
L7	2	(pre$amorphiz$5 or amorphous or amorphiz$3) same depth same first near conductivity and (heat$3 or thermal or anneal$3)same (restor$5 or repair$3 or crystall$5 or re$crystall$3) same depth and ion same second near conductivity and (heat$3 or thermal or anneal$3)and (low near temperature or SPE or solid near phase near epitaxy)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/29 12:42
L8	25	("4617066" | "4683645" | "4837173" | "5168072" | "5254484" | "5320974" | "5397909" | "5607511" | "5789310" | "5885886" | "5899732" | "5998272" | "6008098").PN. OR ("6362063").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2010/01/29 13:15

L9	161	(pre$amorphiz$5 or amorphous or amorphiz$3) same depth and (heat$3 or thermal or anneal$3)same (restor$5 or repair$3 or crystall$5 or re$crystall$3) same depth and junction same shallow$2 and (heat$3 or thermal or anneal$3)and (low near temperature or SPE or solid near phase near epitaxy)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/29 13:23
L10	87	(pre$amorphiz$5 or amorphous or amorphiz$3) same depth and (heat$3 or thermal or anneal$3)same (restor$5 or repair$3 or crystall$5 or re$crystall$3) same depth and junction same shallow$2 and (heat$3 or thermal or anneal$3)and (low near temperature or SPE or solid near phase near epitaxy)and @ad<"20040331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/29 13:25
L11	29	(pre$amorphiz$5 or amorphous or amorphiz$3) same depth and (heat$3 or thermal or anneal$3)same (restor$5 or repair$3 or crystall$5 or re$crystall$3) same depth and junction same shallow$2 and (heat$3 or thermal or anneal$3)and (SPE or solid near phase near epitaxy)and @ad<"20040331"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/29 13:45
L12	30	(pre$amorphiz$5 or amorphous or amorphiz$3) same depth and (heat$3 or thermal or anneal$3)same (restor$5 or repair$3 or crystall$5 or re$crystall$3) same depth and junction same shallow$2 and (heat$3 or thermal or anneal$3)and (SPE or solid near phase near epitaxy)and 438/162-163,201-308,594,519-522,486.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/01/29 14:09

| L13 | 30 | (pre$amorphiz$5 or amorphous or amorphiz$3) same depth and (heat$3 or thermal or anneal$3) same (restor$5 or repair$3 or crystall$5 or re$crystall$3) same depth and junction same shallow$2 and (heat$3 or thermal or anneal$3) and (SPE or solid near phase near epitaxy) and 257/ e21.324,E21.336.ccls. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/01/29 14:13 |

EAST Search History (Interference)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S516	16	(heat$3 or thermal or anneal$3) and amorphous and pn adj junction and (first and third) near depth	US-PGPUB; USPAT; UPAD	OR	ON	2010/01/28 15:42
S515	0	(first and second) near (heat$3 or thermal or anneal$3) and amorphous and pn adj junction and (first and third) near depth	US-PGPUB; USPAT; UPAD	OR	ON	2010/01/28 15:42
S517	1	((heat$3 or thermal or anneal$3) and amorphous and pn adj junction and (first and third) near depth).clm.	US-PGPUB; USPAT; UPAD	OR	ON	2010/01/28 15:48
L14	30	(pre$amorphiz$5 or amorphous or amorphiz $3) same depth and (heat $3 or thermal or anneal $3) same (restor$5 or repair$3 or crystall$5 or re$crystall$3) same depth and junction same shallow$2 and (heat$3 or thermal or anneal$3) and (SPE or solid near phase near epitaxy) and 438/162-163,201-308,594,519-522,486. ccls.	US-PGPUB; USPAT; UPAD	OR	ON	2010/01/29 14:47

L15	30	(pre$amorphiz$5 or amorphous or amorphiz $3)same depth and (heat $3 or thermal or anneal $3)same(restor$5 or repair$3 or crystall$5 or re$crystall$3)same depth and junction same shallow$2 and (heat$3 or thermal or anneal$3)and (SPE or solid near phase near epitaxy)and 257/e21.324,E21.336.ccls.	US-PGPUB; USPAT; UPAD	OR	ON	2010/01/29 14:48
L16	2	(pre$amorphiz$5 or amorphous or amorphiz $3)same depth same first near conductivity and (heat$3 or thermal or anneal$3)same(restor$5 or repair$3 or crystall$5 or re$crystall$3)same depth and ion same second near conductivity and (heat$3 or thermal or anneal$3)and (low near temperature or SPE or solid near phase near epitaxy)	US-PGPUB; USPAT; UPAD	OR	ON	2010/01/29 14:49
L18	1	((pre$amorphiz$5 or amorphous or amorphiz $3)same depth same first near conductivity and (heat$3 or thermal or anneal$3)same(restor$5 or repair$3 or crystall$5 or re$crystall$3)same depth and ion same second near conductivity and (heat$3 or thermal or anneal$3)and (low near temperature or SPE or solid near phase near epitaxy)).clm.	US-PGPUB; USPAT; UPAD	OR	ON	2010/01/29 14:50

L17	2	(pre$amorphiz$5 or amorphous or amorphiz $3)same depth same first near conductivity and (heat$3 or thermal or anneal$3)same(restor$5 or repair$3 or crystall$5 or re$crystall$3)same depth and ion same second near conductivity and (heat$3 or thermal or anneal$3)and (low near temperature or SPE or solid near phase near epitaxy)and 438/162-163,201-308,594,519-522,486.ccls.	US-PGPUB; USPAT; UPAD	OR	ON	2010/01/29 14:50
L20	0	((pre$amorphiz$5 or amorphous or amorphiz $3)same depth and (heat $3 or thermal or anneal $3)same(restor$5 or repair$3 or crystall$5 or re$crystall$3) and junction same shallow$2 and (heat$3 or thermal or anneal$3)and (SPE or solid near phase near epitaxy)).clm.	US-PGPUB; USPAT; UPAD	OR	ON	2010/01/29 14:52
L19	0	((pre$amorphiz$5 or amorphous or amorphiz $3)same depth and (heat $3 or thermal or anneal $3)same(restor$5 or repair$3 or crystall$5 or re$crystall$3)same depth and junction same shallow$2 and (heat$3 or thermal or anneal$3)and (SPE or solid near phase near epitaxy)).clm.	US-PGPUB; USPAT; UPAD	OR	ON	2010/01/29 14:52
L21	27	(pre$amorphiz$5 or amorphous or amorphiz $3)same depth and (heat $3 or thermal or anneal $3)same(restor$5 or repair$3 or crystall$5 or re$crystall$3)same depth and junction same shallow$2 and (heat$3 or thermal or anneal$3)and (SPE or solid near phase near epitaxy)and 438/162-163,301-308,549,519-522,486. ccls.	US-PGPUB; USPAT; UPAD	OR	ON	2010/01/29 15:20

| L22 | 2 | (pre$amorphiz$5 or amorphous or amorphiz $3)same depth same first near conductivity and (heat$3 or thermal or anneal$3)same(restor$5 or repair$3 or crystall$5 or re$crystall$3)same depth and ion same second near conductivity and (heat$3 or thermal or anneal$3)and (low near temperature or SPE or solid near phase near epitaxy)and 438/162-163,301-308,549,519-522,486.ccls. | US-PGPUB; USPAT; UPAD | OR | ON | 2010/01/29 15:21 |

1/29/2010 3:21:53 PM
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